DAN222, NSVDAN222

Common Cathode Silicon **Dual Switching Diode**

This Common Cathode Silicon Epitaxial Planar Dual Diode is designed for use in ultra high speed switching applications. This device is housed in the SOT-416/SC-75 package which is designed for low power surface mount applications, where board space is at a premium.

Features

- Fast t_{rr}
- Low C_D
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS $(T_A = 25^{\circ}C)$

| Rating | Symbol | Value | Unit |
|-------------------------------------|------------------|-------|------|
| Reverse Voltage | V_R | 80 | Vdc |
| Peak Reverse Voltage | V_{RM} | 80 | Vdc |
| Forward Current | I _F | 100 | mAdc |
| Peak Forward Current | I _{FM} | 300 | mAdc |
| Peak Forward Surge Current (Note 1) | I _{FSM} | 2.0 | Adc |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|---------------------------|------------------|-------------|------|
| Power Dissipation | P_{D} | 150 | mW |
| Junction Temperature | TJ | 150 | °C/W |
| Storage Temperature Range | T _{stg} | -55 to +150 | °C |

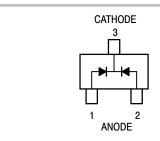
Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. $t = 1 \mu S$



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SC-75/SOT-416 **CASE 463** STYLE 3

MARKING DIAGRAM



N9 = Specific Device Code

Μ = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location) *Date Code orientation may vary depending upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|--------------|--------------------|-----------------------|
| DAN222G | SC-75 (Pb-Free) | 3000 / Tape & Reel |
| DAN222T1G | SC-75 (Pb-Free) | 3000 / Tape & Reel |
| NSVDAN222T1G | SC-75 (Pb-Free) | 3000 / Tape & Reel |

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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ELECTRICAL CHARACTERISTICS (T_A = 25°C)

| Characteristic | Symbol | Condition | Min | Max | Unit |
|---------------------------------|--------------------------|--|-----|-----|------|
| Reverse Voltage Leakage Current | I _R | V _R = 70 V | - | 0.1 | μAdc |
| Forward Voltage | V _F | I _F = 100 mA | _ | 1.2 | Vdc |
| Reverse Breakdown Voltage | V_{R} | I _R = 100 μA | 80 | - | Vdc |
| Diode Capacitance | C _D | V _R = 6.0 V, f = 1.0 MHz | - | 3.5 | pF |
| Reverse Recovery Time | t _{rr} (Note 2) | I_F = 5.0 mA, V_R = 6.0 V, R_L = 100 Ω , I_{rr} = 0.1 I_R | - | 4.0 | ns |

^{2.} t_{rr} Test Circuit on following page.

TYPICAL ELECTRICAL CHARACTERISTICS

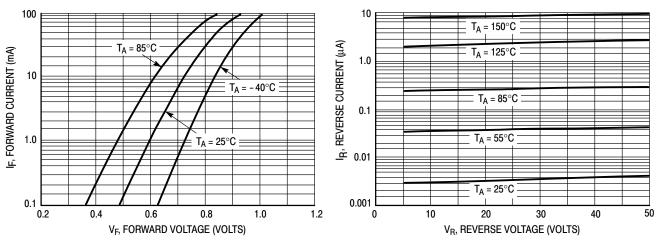


Figure 1. Forward Voltage

Figure 2. Reverse Current

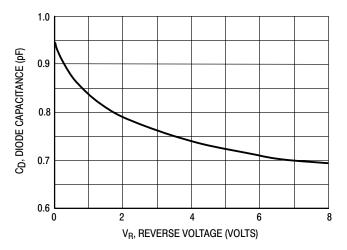


Figure 3. Diode Capacitance

DAN222, NSVDAN222

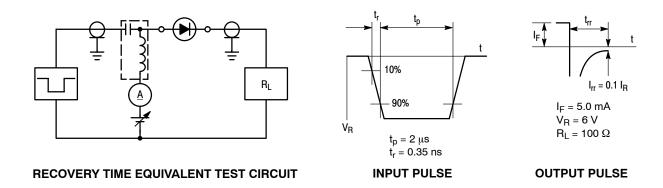


Figure 4. Reverse Recovery Time Test Circuit for the DAN222



SC75-3 1.60x0.80x0.80, 1.00P **CASE 463 ISSUE H**

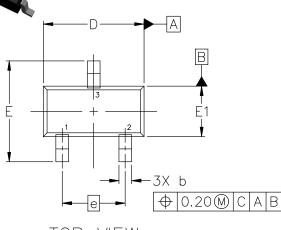
DATE 01 FEB 2024

NOTES:

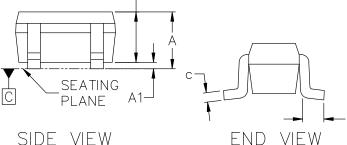
- DIMENSIONING AND TOLERANCING CONFORM TO ASME Y14.5-2018.
- ALL DIMENSION ARE IN MILLIMETERS.

| DIM | MILLIMETERS | | | |
|---------|-------------|------|------|--|
| I UIIVI | MIN. | NOM. | MAX. | |
| А | 0.70 | 0.80 | 0.90 | |
| A1 | 0.00 | 0.05 | 0.10 | |
| A2 | 0.80 REF. | | | |
| b | 0.15 | 0.20 | 0.30 | |
| С | 0.10 | 0.15 | 0.25 | |
| D | 1.55 | 1.60 | 1.65 | |
| E | 1.50 | 1.60 | 1.70 | |
| E1 | 0.70 | 0.80 | 0.90 | |
| е | 1.00 BSC | | | |
| L | 0.10 | 0.15 | 0.20 | |
| | | | | |

0.356



VIEW



A2

SIDE VIEW

GENERIC MARKING DIAGRAM*



XX= Specific Device Code

Μ = Date Code

= Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "■", may or may not be present. Some products may not follow the Generic Marking.

STYLE 1: PIN 1. BASE 2. EMITTER

PIN 1. CATHODE 2. CATHODE

3. ANODE

STYLE 4:

STYLE 2: PIN 1. ANODE 2. N/C

PIN 1. GATE 2. SOURCE

3. DRAIN

STYLE 3: PIN 1. ANODE 2. ANODE 3. CATHODE

3. COLLECTOR 3. CATHODE STYLE 5:

1.803 0.787 0.508 1.000

RECOMMENDED MOUNTING FOOTPRINT*

FOR ADDITIONAL INFORMATION ON OUR Pb-FREE STRATEGY AND SOLDERING DETAILS, PLEASE DOWNLOAD THE ON SEMICONDUCTOR SOLDERING AND MOUNTING TECHNIQUES REFERENCE MANUAL, SOLDERRM/D.

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|------------------|----------------------------|--|-------------|
| DESCRIPTION: | SC75-3 1.60x0.80x0.80, 1.0 | 00P | PAGE 1 OF 1 |

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